

# RF Exposure Evaluation Report

<b>Product</b>	: PanBrain Energy Capsule II
<b>Trade mark</b>	: N/A
<b>Model/Type reference</b>	: Lotus-2
<b>Serial Number</b>	: N/A
<b>Report Number</b>	: EED32Q80484803
<b>FCC ID</b>	: 2BDHC-LOTUS2
<b>Date of Issue</b>	: Jul. 01, 2024
<b>Test Standards</b>	: 47 CFR Part 1.1307 47 CFR Part 1.1310 47 CFR Part 2.1091 47 CFR Part 2.1093 447498 D04 Interim General RF Exposure Guidance v01
<b>Test result</b>	: PASS

Prepared for:

**Shenzhen PanBrain Technology Co., Ltd.****Room A2801, 28th floor, east building, digital culture industry base,  
Nanshan District, Shenzhen, China**

Prepared by:

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Date:

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**2 Version**

Version No.	Date	Description
00	Jul. 01, 2024	Original

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## 4 General Information

### 4.1 Client Information

Applicant:	Shenzhen PanBrain Technology Co., Ltd.
Address of Applicant:	Room A2801, 28th floor, east building, digital culture industry base, Nanshan District, Shenzhen, China
Manufacturer:	Shenzhen PanBrain Technology Co., Ltd.
Address of Manufacturer:	Room A2801, 28th floor, east building, digital culture industry base, Nanshan District, Shenzhen, China
Factory:	Shenzhen PanBrain Technology Co., Ltd.
Address of Factory:	Room A2801, 28th floor, east building, digital culture industry base, Nanshan District, Shenzhen, China

### 4.2 General Description of EUT

Product Name:	PanBrain Energy Capsule II
Model No.(EUT):	Lotus-2
Trade Mark:	N/A

### 4.3 Product Specification subjective to this standard

Frequency Range:	2402MHz~2480MHz
Modulation Type:	BLE: GFSK BT: GFSK, π/4DQPSK, 8DPSK
Test Power Grade:	Default
Test Software of EUT:	BT_Tool
Antenna Type:	PCB Antenna
Antenna Gain:	1.7dBi
Power Supply:	5V/2A (by USB); 7.4VDC(by Rechargeable Lithium-ion Battery)
Sample Received Date:	Apr. 15, 2024
Sample tested Date:	Jun. 06, 2024 to Jun. 18, 2024
Remark:	<p>This product have various external enclosure colors.</p> <p>Company Name and Address shown on Report, the sample(s) and sample Information were provided by the applicant who should be responsible for the authenticity which CTI hasn't verified.</p>

#### 4.4 Test Location

All tests were performed at:

Centre Testing International Group Co., Ltd  
Building C, Hongwei Industrial Park Block 70, Bao'an District, Shenzhen, China  
Telephone: +86 (0) 755 33683668 Fax:+86 (0) 755 33683385

No tests were sub-contracted.

FCC Designation No.: CN1164

#### 4.5 Deviation from Standards

None.

#### 4.6 Abnormalities from Standard Conditions

None.

#### 4.7 Other Information Requested by the Customer

None.

## 5 SAR Evaluation

### 5.1 RF Exposure Compliance Requirement

#### 5.1.1 Limits

The SAR-based exemption formula of § 1.1307(b)(3)(i)(B), repeated here as Formula (B.2), applies for single fixed, mobile, and portable RF sources with available maximum time-averaged power or effective radiated power (ERP), whichever is greater, of less than or equal to the threshold  $P_{th}$  (mW).

This method shall only be used at separation distances from 0.5 cm to 40 cm and at frequencies from 0.3 GHz to 6 GHz (inclusive).  $P_{th}$  is given by Formula

$$P_{th} \text{ (mW)} = \begin{cases} ERP_{20 \text{ cm}}(d/20 \text{ cm})^x & d \leq 20 \text{ cm} \\ ERP_{20 \text{ cm}} & 20 \text{ cm} < d \leq 40 \text{ cm} \end{cases}$$

where

$$x = -\log_{10} \left( \frac{60}{ERP_{20 \text{ cm}} \sqrt{f}} \right)$$

and  $f$  is in GHz,  $d$  is the separation distance (cm), and  $ERP_{20\text{cm}}$  is per Formula (B.1).

$$P_{th} \text{ (mW)} = ERP_{20 \text{ cm}} \text{ (mW)} = \begin{cases} 2040f & 0.3 \text{ GHz} \leq f < 1.5 \text{ GHz} \\ 3060 & 1.5 \text{ GHz} \leq f \leq 6 \text{ GHz} \end{cases} \quad (\text{B.1})$$

The 1 mW Blanket Exemption of § 1.1307(b)(3)(i)(A) applies for single fixed, mobile, and portable RF sources with available maximum time-averaged power of no more than 1 mW, regardless of separation distance.

#### 5.1.2 Test Procedure

Software provided by client enabled the EUT to transmit and receive data at lowest, middle and highest channel individually.

**5.1.3 EUT RF Exposure Evaluation****For Stand alone:****For BLE**

Frequency (MHz)	Max. Conducted Output power (dBm)	Antenna Gain (dBi)	EIRP (dBm)	ERP (dBm)	ERP (mW)	Limit (mW)	Result
2480	0.56	1.7	2.26	0.11	1.026	2.717	PASS

**For BT**

Frequency (MHz)	Max. Conducted Output power (dBm)	Antenna Gain (dBi)	EIRP (dBm)	ERP (dBm)	ERP (mW)	Limit (mW)	Result
2480	1.49	1.7	3.19	1.04	1.271	2.717	PASS

**Note:**

- ①EIRP=conducted power+antenna gain;
- ②ERP=EIRP-2.15;
- ③EIRP(dBm) = Field strength of the fundamental signal(dBuV/m@3m) – 95.23;
- ④ERP(mW) =  $10^{(ERP\ (dBm)/10)}$ ;
- ⑤The estimation distance is 0.5cm;
- ⑥The test data please refer to the report of EED32Q80484801, EED32Q80484802 and only the worst case data was recorded in the report.

The test report is effective only with both signature and specialized stamp, The result(s) shown in this report refer only to the sample(s) tested. Without written approval of CTI, this report can't be reproduced except in full.

**\*\*\* End of Report \*\*\***